VS-U5FH240FA120

Vishay Semiconductors



FRED Pt[®] Gen 5 Ultrafast Rectifier Diode, 1200 V, 240 A



| PRIMARY CHARACTERISTICS | | | | | | | |
|--|---------------------------------------|--|--|--|--|--|--|
| V _R | 1200 V | | | | | | |
| V _F (typical) at 120 A, per diode | 1.99 V | | | | | | |
| t _{rr} (typical) at 120 A, per diode | 98 ns | | | | | | |
| $I_{F(DC)}$ per module at $T_C = 75 \ ^{\circ}C$ | 240 A | | | | | | |
| Туре | Modules - diode FRED Pt® | | | | | | |
| Package | SOT-227 | | | | | | |
| Circuit configuration | Two separate diodes, parallel pin-out | | | | | | |

FEATURES

- Ultrafast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- ROHS COMPLIANT
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, the VS-U5FH240FA120 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|-----------------------------------|---------------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | |
| Cathode to anode voltage | V _R | | 1200 | V | | |
| Continuous forward current per diode | I _F | T _C = 75 °C | 120 | ۸ | | |
| Single pulse forward current per diode | I _{FSM} | $T_J = 25 \ ^{\circ}C$ | 665 | A | | |
| Maximum power dissipation per module | PD | T _C = 75 °C | 526 | W | | |
| RMS isolation voltage | V _{ISOL} | Any terminal to case, t = 1 min | 2500 | V | | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +175 | °C | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|-----------------|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Cathode to anode breakdown voltage | V _{BR} | I _R = 200 μA | 1200 | - | - | | |
| Forward voltage | V _{FM} | I _F = 120 A | - | 1.99 | 2.5 | V | |
| | | I _F = 120 A, T _J = 150 °C | - | 1.74 | - | | |
| | | V _R = 1200 V | - | 0.9 | 160 | | |
| Reverse leakage current | I _{RM} | T _J = 125 °C, V _R = 1200 V | - | 228 | - | μA | |
| | | T _J = 150 °C, V _R = 1200 V | - | 684 | - | | |

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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | |
|---|------------------|-------------------------|---|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST | CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Powerse receivery time | + | $T_J = 25 \ ^\circ C$ | | - | 98 | - | ns | |
| Reverse recovery time | t _{rr} | T _J = 125 °C | | - | 174 | - | | |
| De als ve a sur au mart | | T _J = 25 °C | $ I_F = 120 \text{ A}, \\ di_F/dt = 1000 \text{ A}/\mu\text{s}, \\ V_R = 800 \text{ V} $ | - | 38 | - | A | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 70 | - | | |
| Devenue an example al entre | 0 | T _J = 25 °C | | - | 3.4 | - | μC | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 9.5 | - | μΟ | |
| Junction capacitance | CT | $V_{R} = 1200 V$ | | - | 41.7 | - | pF | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---|-------------------|-----------------------|------|------|------------|-------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Thermal resistance junction to case, per diode | | | - | - | 0.38 | | |
| Thermal resistance junction to case, per module | R _{thJC} | | - | - | 0.19 | °C/W | |
| Thermal resistance case to heatsink, per module | R _{thCS} | Flat, greased surface | - | 0.05 | - | | |
| Weight | | | - | 30 | - | g | |
| Manuation to serve | | Torque per diode | - | - | 1.1 (9.7) | Nm (lbf.in) | |
| Mounting torque | | Torque to heatsink | - | - | 1.8 (15.9) | Nm (lbf.in) | |
| Case style | | | | SO | Г-227 | • | |



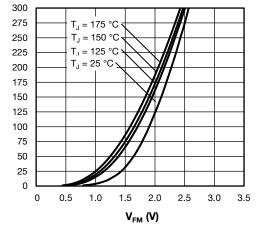


Fig. 1 - Typical Forward Voltage Drop Characteristics

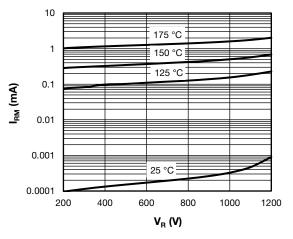


Fig. 2 - Typical Values of Reverse Current



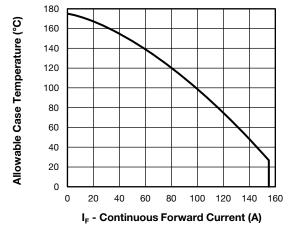


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Diode)

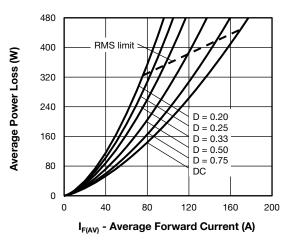


Fig. 4 - Average Power Loss vs. Average Forward Current

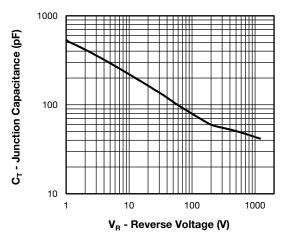
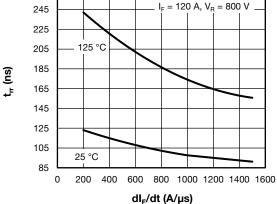


Fig. 5 - Junction Capacitance vs. Reverse Voltage

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Fig. 6 - Diode Reverse Recovery Time vs. dl_Fdt

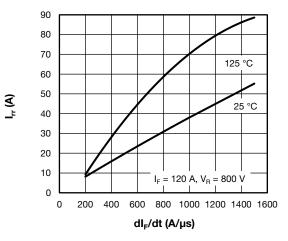


Fig. 7 - Diode Reverse Recovery Current vs. dl_Fdt

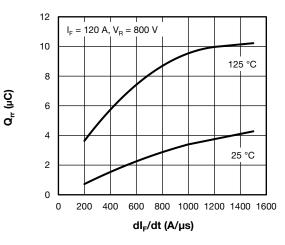


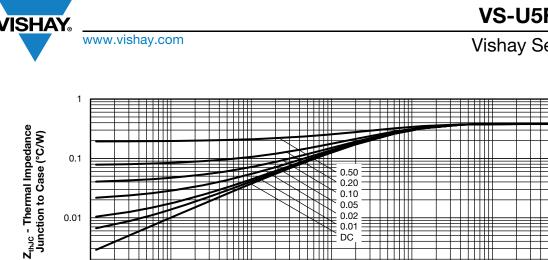
Fig. 8 - Diode Reverse Recovery Charge vs. dl_Fdt

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0.001

DC +++ ╈ Ħ

0.1

1

t₁ - Rectangular Pulse Duration (s)

0.01

Fig. 9 - Maximum Thermal Impedance Junction to Case

ORDERING INFORMATION TABLE

0.0001

0.001 0.00001

| Device code | vs- | U5F | н | 240 | F | Α | 120 | |
|-------------|-------------|-------|---------|-------------------------------|---------------------|----------|-----|--|
| | | 2 | (3) | 4 | 5 | 6 | (7) | |
| | 1 2 3 | - U5F | = Gen | niconduo 5 FRED st FRED | Pt [®] far | nily | | |
| | 4 | | | ing (240 | | , | | |
| | 5 6 7 | - Pac | kage in | • | (SOT-22 | 27 stand | | des, parallel pin-out) ulated base) |

| CIRCUIT CONFIGURATION | | | | | |
|--|-------------------------------|---|--|--|--|
| CIRCUIT | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING | | | |
| Two separate diodes, parallel pin-out | F | Lead Assignment 4 1 1 1 1 1 1 1 1 1 1 1 1 1 | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?95423 | | | | |
| Packaging information | www.vishay.com/doc?95425 | | | | |
| | | | | | |

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SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

• Controlling dimension: millimeter



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Revision: 01-Jan-2025

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